

DARLINGTON SILICON POWER TRANSISTORS

...designed for general-purpose amplifier and low speed switching applications

FEATURES:

- * Collector-Emitter Sustaining Voltage-

$V_{CEO(SUS)} = 40$ V (Min) - 2N6386

= 60 V (Min) - 2N6387

= 80 V (Min) - 2N6388

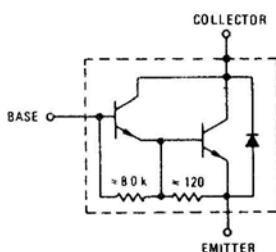
- * Collector-Emitter Saturation Voltage

$V_{CE(sat)} = 2.0$ V (Max.) @ $I_C = 3.0$ A - 2N6386

= 2.0 V (Max.) @ $I_C = 5.0$ A - 2N6387, 2N6388

- * DC Current Gain $hFE = 2500$ (Typ) @ $I_C = 4.0$ A

- * Complementary to 2N6666, 2N6667, 2N6668



NPN

2N6386

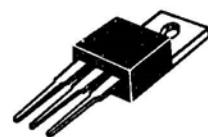
2N6387

2N6388

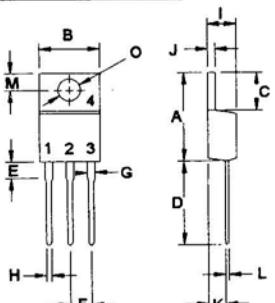
8 AND 10 AMPERE
DARLINGTON
POWER TRANSISTORS
NPN SILICON
40-80 VOLTS
65 WATTS

MAXIMUM RATINGS

Characteristic	Symbol	2N6386	2N6387	2N6388	Unit
Collector-Emitter Voltage	V_{CEO}	40	60	80	V
Collector-Base Voltage	V_{CBO}	40	60	80	V
Emitter-Base Voltage	V_{EBO}		5.0		V
Collector Current-Continuous -Peak	I_C I_{CM}	8.0 15	10 15	10 15	A
Base Current	I_B		0.25		A
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D		65 0.52		W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{STG}		- 65 to +150		$^\circ\text{C}$



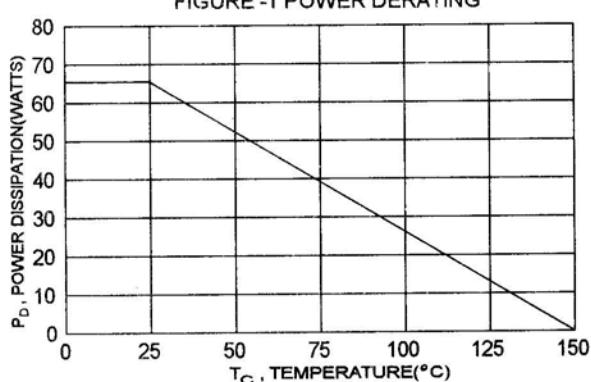
TO-220



PIN 1.BASE
2.COLLECTOR
3.EMITTER
4.COLLECTOR(CASE)

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	16.00
B	9.78	10.42
C	5.02	6.60
D	13.00	14.62
E	3.10	4.19
F	2.41	2.67
G	1.10	1.67
H	0.69	1.01
I	3.21	4.98
J	1.14	1.40
K	2.20	3.30
L	0.28	0.61
M	2.48	3.00
O	3.50	4.00

FIGURE -1 POWER DERATING



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ELECTRICAL CHARACTERISTICS ($T_c = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector - Emitter Sustaining Voltage (1) ($I_c = 200 \text{ mA}$, $I_b = 0$)	$V_{CEO(\text{sus})}$	40 60 80		V
Collector Cutoff Current ($V_{CE} = 40 \text{ V}$, $I_b = 0$) ($V_{CE} = 60 \text{ V}$, $I_b = 0$) ($V_{CE} = 80 \text{ V}$, $I_b = 0$)	I_{CEO}		1.0 1.0 1.0	mA
Collector Cutoff Current ($V_{CE} = 40 \text{ V}$, $V_{BE(\text{OFF})} = 1.5 \text{ V}$) ($V_{CE} = 60 \text{ V}$, $V_{BE(\text{OFF})} = 1.5 \text{ V}$) ($V_{CE} = 80 \text{ V}$, $V_{BE(\text{OFF})} = 1.5 \text{ V}$) ($V_{CE} = 40 \text{ V}$, $V_{BE(\text{OFF})} = 1.5 \text{ V}$, $T_c = 125^\circ\text{C}$) ($V_{CE} = 60 \text{ V}$, $V_{BE(\text{OFF})} = 1.5 \text{ V}$, $T_c = 125^\circ\text{C}$) ($V_{CE} = 80 \text{ V}$, $V_{BE(\text{OFF})} = 1.5 \text{ V}$, $T_c = 125^\circ\text{C}$)	I_{CEX}		0.3 0.3 0.3 3.0 3.0 3.0	mA
Emitter Cutoff Current ($V_{EB} = 5.0 \text{ V}$, $I_c = 0$)	I_{EBO}		5.0	mA

ON CHARACTERISTICS (1)

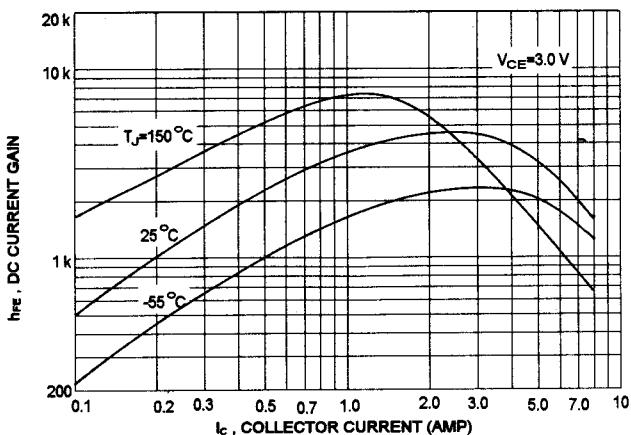
DC Current Gain ($I_c = 3.0 \text{ A}$, $V_{CE} = 3.0 \text{ V}$) ($I_c = 5.0 \text{ A}$, $V_{CE} = 3.0 \text{ V}$) ($I_c = 8.0 \text{ A}$, $V_{CE} = 3.0 \text{ V}$) ($I_c = 10 \text{ A}$, $V_{CE} = 3.0 \text{ V}$)	2N6386 2N6387, 2N6388 2N6386 2N6387, 2N6388	h_{FE}	1000 1000 100 100	20000 20000	
Collector-Emitter Saturation Voltage ($I_c = 3.0 \text{ A}$, $I_b = 6 \text{ mA}$) ($I_c = 5.0 \text{ A}$, $I_b = 10 \text{ mA}$) ($I_c = 8.0 \text{ A}$, $I_b = 80 \text{ mA}$) ($I_c = 10 \text{ A}$, $I_b = 100 \text{ mA}$)	2N6386 2N6387, 2N6388 2N6386 2N6387, 2N6388	$V_{CE(\text{sat})}$		2.0 2.0 3.0 3.0	V
Base-Emitter On Voltage ($I_c = 3.0 \text{ A}$, $V_{CE} = 3.0 \text{ V}$) ($I_c = 5.0 \text{ A}$, $V_{CE} = 3.0 \text{ V}$) ($I_c = 8.0 \text{ A}$, $V_{CE} = 3.0 \text{ V}$) ($I_c = 10 \text{ A}$, $V_{CE} = 3.0 \text{ V}$)	2N6386 2N6387, 2N6388 2N6386 2N6387, 2N6388	$V_{BE(\text{on})}$		2.8 2.8 4.5 4.5	V

DYNAMIC CHARACTERISTICS

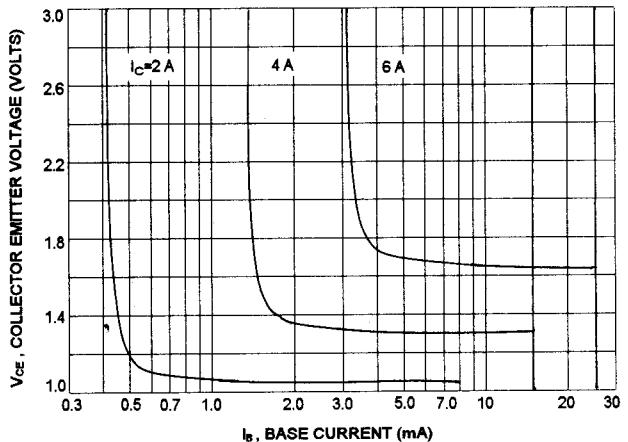
Small-Signal Current Gain ($I_c = 1.0 \text{ A}$, $V_{CE} = 5.0 \text{ V}$, $f = 1.0 \text{ KHz}$)	h_{fe}	1000		
Output Capacitance ($V_{CB} = 10 \text{ V}$, $I_E = 0$, $f = 1.0 \text{ MHZ}$)	C_{ob}		200	pF

(1) Pulse Test: Pulse width = 300 μs , Duty Cycle $\leq 2.0\%$ FLYING 汇翔国际有限公司
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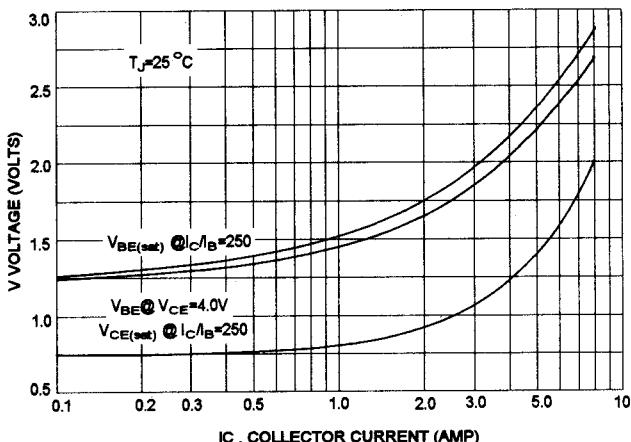
DC CURRENT GAIN



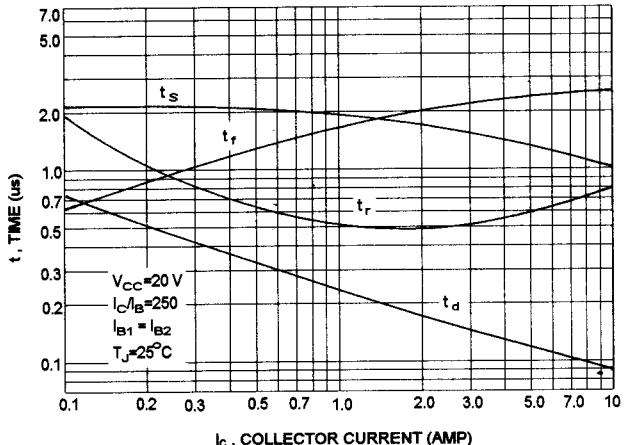
COLLECTOR SATURATION REGION



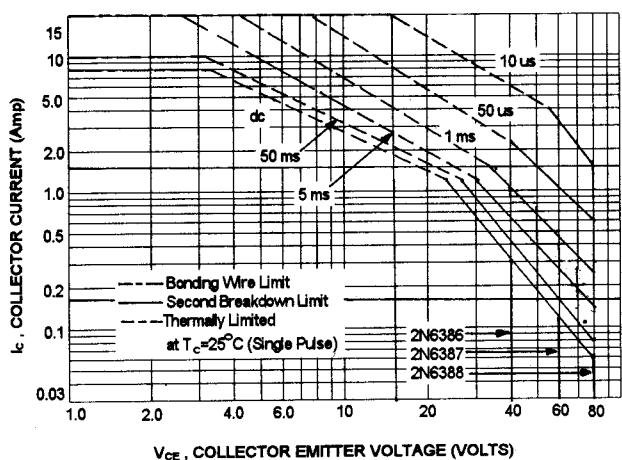
"ON" VOLTAGES



SWITCHING TIME



ACTIVE-REGION SAFE OPERATING AREA (SOA)



There are two limitation on the power handling ability of a transistor: average junction temperature and second breakdown safe operating area curves indicate I_C-V_{CE} limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of SOA curve is base on $T_{J(PK)}=150^\circ C$; T_c is variable depending on conditions. second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(PK)} \leq 150^\circ C$. At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

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